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Luminescence regulation of Sb^{3+} in 0D hybrid metal halides by hydrogen bond network for optical anti-counterfeiting

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Binbin Luo^{3*}, Wensi Cai¹, Qingkai Qian¹ and Zhigang Zang^{1*}

The Sb^{3+} doping strategy has been proven to be an effective way to regulate the band gap and improve the photophysical properties of organic-inorganic hybrid metal halides (OIHMHs). However, the emission of Sb^{3+} ions in OIHMHs is primarily confined to the low energy region, resulting in yellow or red emissions. To date, there are few reports about green emission of Sb^{3+} -doped OIHMHs. Here, we present a novel approach for regulating the luminescence of Sb^{3+} ions in 0D $\text{C}_{10}\text{H}_{22}\text{N}_6\text{InCl}_7 \cdot \text{H}_2\text{O}$ via hydrogen bond network, in which water molecules act as agents for hydrogen bonding. Sb^{3+} -doped $\text{C}_{10}\text{H}_{22}\text{N}_6\text{InCl}_7 \cdot \text{H}_2\text{O}$ shows a broadband green emission peaking at 540 nm and a high photoluminescence quantum yield (PLQY) of 80%. It is found that the intense green emission stems from the radiative recombination of the self-trapped excitons (STEs). Upon removal of water molecules with heat, $\text{C}_{10}\text{H}_{22}\text{N}_6\text{In}_{1-x}\text{Sb}_x\text{Cl}_7$ generates yellow emission, attributed to the breaking of the hydrogen bond network and large structural distortions of excited state. Once water molecules are adsorbed by $\text{C}_{10}\text{H}_{22}\text{N}_6\text{In}_{1-x}\text{Sb}_x\text{Cl}_7$, it can subsequently emit green light. This water-induced reversible emission switching is successfully used for optical security and information encryption. Our findings expand the understanding of how the local coordination structure influences the photophysical mechanism in Sb^{3+} -doped metal halides and provide a novel method to control the STEs emission.

Keywords: indium-based halides; Sb^{3+} doping; hydrogen bonding network; optical anti-counterfeiting

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Introduction

Organic-inorganic hybrid metal halides (OIHMHs) are emerging semiconductor materials that exhibit excellent optoelectronic properties, making them a particularly suitable choice for the development of optoelectronic devices, including lasers, scintillators, photodetectors

and light emitting diodes (LEDs)¹⁻⁷. In OIHMHs, the valence and conduction bands are primarily formed by the orbital hybridization between metal ions and halogen ions⁸⁻¹⁴. As a result, the optical properties of OIHMHs predominantly depend on the specie of metal and halogen ions^{15,16}.

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Due to the typical $5s^2$ electron configuration of Sb^{3+} , Sb^{3+} -doping has been proven to be an effective method to tune the photophysical properties of OIHMHS by regulating the band structure of metal halides^{17,18}. A series of Sb^{3+} -doped $(C_9H_{15}N_3)_2SnCl_8$ was reported by Liu et al. using the cooling crystallization method¹⁹. Upon excitation with ultraviolet (UV) light at room temperature, Sb^{3+} -doped $(C_9H_{15}N_3)_2SnCl_8$ displayed red emission centered at 688 nm as well as an increase of photoluminescence quantum yield (PLQY) from 1% to 17.84%, attributed to the enhancement of self-trapped excitons (STEs) emission of Sb^{3+} dopant. Zou *et al.* have reported a series of zero-dimensional (0D) hybrid metal halides based on Sb^{3+} -doped tin(IV) compounds, denoted as $(C_{13}H_{30}N)_2SnCl_6:x\%Sb$ ²⁰. Among these compounds, $(C_{13}H_{30}N)_2SnCl_6:20\%Sb$ exhibits a bright red emission with a PLQY of 80.98% when excited at 380 nm under room temperature. Apart from Sn(IV)-based halides, Sb^{3+} doping has also been employed to enhance the optical property of Cd-based and In-based metal halide. For example, Sb^{3+} -doped $[NH_3(CH_2)_4NH_3]CdBr_4$ exhibited an intense orange emission at approximately 640 nm²¹. This material demonstrated a large Stokes shift of approximately 1.33 eV and a full width at half-maximum (FWHM) of around 0.45 eV. Upon introducing 0.01% Sb doping, the PLQY of $[NH_3(CH_2)_4NH_3]CdBr_4$ approached near-unity, reaching approximately 97%. Furthermore, 0D MA_4InCl_7 [MA^+ : $CH_3NH_3^+$] halides with varying doping levels of Sb^{3+} were prepared using a solvent evaporation method²². MA_4InCl_7 doped with Sb^{3+} exhibits a broadband yellow emission with a FWHM of 180 nm and a high PLQY of 84%. However, because 0D metal halides lead a large distortion of $[SbX_6]^{3-}$ in the excited states, the emission of Sb^{3+} ions in these cases is primarily located in yellow or red range. Compared to all inorganic metal halides, OIHMHS have a soft crystal lattice which is easy to lattice distortion. To date, there are few reports about green emission based on Sb^{3+} in hybrid metal halides. Thus, it is still a challenge to realize the green light emission from such Sb^{3+} doped OIHMHS.

In this work, a new strategy was proposed to control the luminescence of STEs in the inorganic clusters by tuning the hydrogen bond network in the crystal structure. 0D lead-free $C_{10}H_{22}N_6InCl_7 \cdot H_2O$ and Sb^{3+} -doped $C_{10}H_{22}N_6InCl_7 \cdot H_2O$ were synthesized using an anti-solvent diffusion method. The hydrogen bonding in $C_{10}H_{22}N_6InCl_7 \cdot H_2O$ is mediated by water guest molecules to form a network of hydrogen bonds. When Sb^{3+}

is introduced into the metal halides, Sb^{3+} doped $C_{10}H_{22}N_6InCl_7 \cdot H_2O$ shows an intense broadband green emission peaking at 540 nm and a high PLQY of 80%. The strong electron-phonon coupling in the 0D crystal-line structures of Sb^{3+} doped $C_{10}H_{22}N_6InCl_7 \cdot H_2O$ is believed to result in broadband green light emission originating from STEs. The hydrogen bond network limits the structural distortion of the excited state of the inorganic cluster, which plays an important role in the green light emission of Sb^{3+} doped $C_{10}H_{22}N_6InCl_7 \cdot H_2O$. However, breaking the hydrogen bond network with the help of heat causes Sb^{3+} -doped $C_{10}H_{22}N_6InCl_7$ to emit a yellow light. This reversible emission changes can be utilized in information encryption and anti-counterfeiting. Our findings expand the understanding of how the local coordination structure influences the photophysical mechanism in Sb^{3+} -doped OIHMHS and provide a novel method to control the STEs emission.

Materials and methods

Materials

Diantimony trioxide (Sb_2O_3 , SP, Macklin), Indium (III) oxide (In_2O_3 , 99.99%, Meryer), Hydrochloric acid (HCl, AR, Chongqing Chuandong Chemical), Histamine dihydrochloride ($C_5H_{11}N_3Cl_2$, 98%, Meryer), Ethanol (99.8%, Boer) and Polymethyl methacrylate (PMMA, Sigma Corp) were used without any further purification.

Synthesis of $C_{10}H_{22}N_6InCl_7 \cdot H_2O$

In_2O_3 (0.069 g, 0.25 mmol) and histamine dihydrochloride (0.368 g, 2.0 mmol) were dissolved in 1.0 mL HCl solution and then filtered into a 20 mL vial to form a clear precursor solution. Then, the vial was placed in a 100 mL vial with 60 mL EtOH inside. The as-prepared solution was sealed and left to stand for ~3 days to afford pale block crystals.

Synthesis of $C_5H_{11}N_3SbCl_5$

Sb_2O_3 (0.138 g, 0.5 mmol) and histamine dihydrochloride (0.184 g, 1.0 mmol) in 1 mL HCl solution and then filtered into a 20 mL vial to form a clear precursor solution. Then, the vial was placed in a 100 mL vial with 60 mL EtOH inside. The as-prepared solution was sealed and left to stand for ~3 days to afford pale block crystals.

Synthesis of $C_{10}H_{22}N_6In_{1-x}Sb_xCl_7 \cdot H_2O$

For the synthesis of $C_{10}H_{22}N_6In_{1-x}Sb_xCl_7 \cdot H_2O$,

Sb₂O₃/In₂O₃ aqueous solutions with designed compositions were used and the other conditions were kept invariable to obtain the corresponding crystals.

Characterizations

Single crystal XRD (calculated XRD) was carried out on a microfocal spot X-ray single crystal diffractometer (SuperNova, Agilent Technologies, Poland). The powder X-ray diffraction (XRD) patterns were measured using a Cu K α radiation (XRD-6100, SHIMADZU, Japan). UV-vis Absorption spectra were collected on a UV-vis spectrophotometer (UV-vis: UV-3600, SHIMADZU, Japan). The steady and transient state PL spectroscopies were measured by a fluorescence spectrometer (FLS1000, Edinburgh Instruments Ltd., England). XPS spectra were collected from an ESCA Lab220I-XL. Raman spectra were collected from LabRAM HR Evolution. SEM and EDS mapping were collected from Jieke TESCAN MIRA LMS.

First-principles calculations

The electronic band structures and wave functions of C₁₀H₂₂N₆InCl₇·H₂O, Sb³⁺ doped C₁₀H₂₂N₆InCl₇·H₂O, Sb³⁺ doped C₁₀H₂₂N₆InCl₇ and C₅H₁₁N₃SbCl₅ were calculated using density functional theory (DFT) implemented on the Vienna ab initio simulation package (VASP). Generalized gradient approximation (GGA) of Perdew-Burke-Ernzerhof (PBE) exchange-correlation functional and pseudopotential with the projector augmented wave (PAW) method were used. The kinetic energy cutoff was set as 400 eV. The electronic wave function was self-consistently converged with energy variation criteria of 10⁻⁵ eV. The atomic structure was relaxed with 2 × 2 × 4 Gamma-center k-point mesh and the atomic force criteria of 0.005 eV/Å. The density of states (DOS) and orbital-resolved partial densities of states (PDOS) were obtained by sampling the Brillouin zone with 2 × 2 × 4 Gamma-center k-point mesh and Gaussian smearing width of 0.05 eV. Band structures are calculated along high symmetry lines of crystal structure with space group *P*₂₁/*c* and *P*₂₁/*n*, based on which transition dipole moments are calculated using VASPKIT.

Results and discussion

C₁₀H₂₂N₆InCl₇·H₂O single crystals were prepared using an antisolvent diffusion method with C₅H₁₁N₃Cl₂ and In₂O₃ in an aqueous solution of hydrochloric acid (HCl) and ethanol as a slowly-diffusing antisolvent.

C₁₀H₂₂N₆InCl₇·H₂O crystalizes in a monoclinic *P*₂₁/*c* space group, and the structure features In-Cl octahedral units coordinated by six chlorine atoms, as shown in Fig. 1(a) and Table S1. Furthermore, the crystal structure exhibits a hydrogen bonding network among H₂O molecules, C₅H₁₁N₃²⁺ cation and [InCl₆]³⁻ octahedral unit (Fig. S1). As shown in Fig. S2, the obtained powder X-ray diffraction (PXRD) pattern matches well with the simulated pattern, confirming the high crystal purity.

Under 365 nm excitation, C₁₀H₂₂N₆InCl₇·H₂O exhibits blue emission with a PLQY of 9.8% and a corresponding photoluminescence (PL) peak at ~430 nm (Fig. S3). What's more, the PL decay curve of C₁₀H₂₂N₆InCl₇·H₂O can be fitted with a single exponential function, yielding an average lifetime of 1.8 μs (Fig. S4). To confirm the origin of blue emission, we synthesized the organic hydrochloride counterpart, i.e., C₅H₁₁N₃Cl₂. The C₅H₁₁N₃Cl₂ crystals also show a blue emission centered at 425 nm with a PL lifetime of 1.5 μs (Fig. S5). Thus, it can be reasonably inferred that C₁₀H₂₂N₆InCl₇·H₂O and C₅H₁₁N₃Cl₂ crystals possess a same phosphorescent mechanism, resulting from the C₅H₁₁N₃²⁺ organic cation.

Doping is an effective strategy for introducing outstanding photoelectric properties in semiconductor materials. By partially replacing In₂O₃ with Sb₂O₃, a series of Sb³⁺ doped C₁₀H₂₂N₆InCl₇·H₂O crystals were successfully synthesized. Figure 1(b) illustrates that the C₁₀H₂₂N₆In_{1-x}Sb_xCl₇·H₂O crystals appear as colorless under visible light, resembling the original C₁₀H₂₂N₆InCl₇·H₂O. As the Sb content gradually increases from 0 to 30%, C₁₀H₂₂N₆In_{1-x}Sb_xCl₇·H₂O shows an intense green emission. Subsequently, the photophysical properties of the samples at room temperature were thoroughly investigated. In Fig. 1(c), the PLQY data for the series of samples are plotted as a function of the content of Sb. It is observed that all Sb-doped samples have a higher PLQY than that of the undoped compounds, C₁₀H₂₂N₆InCl₇·H₂O and C₅H₁₁N₃SbCl₅. The incorporated of Sb³⁺ ions enable the formation of [SbCl₆]³⁻ octahedra, which serve as active emission centers in doped crystals. It has been reported that the [SbCl₆]³⁻ octahedra correspond to efficient STEs emission with high PLQY^{23,24}. Therefore, in this work, the incorporation of Sb³⁺ dopants results in the increase of PLQY up to 80%, and the PLQY value is found to reduce when incorporating a large amount of Sb dopants, which is ascribed to concentration quenching^{25,26}. C₅H₁₁N₃SbCl₅ crystalizes

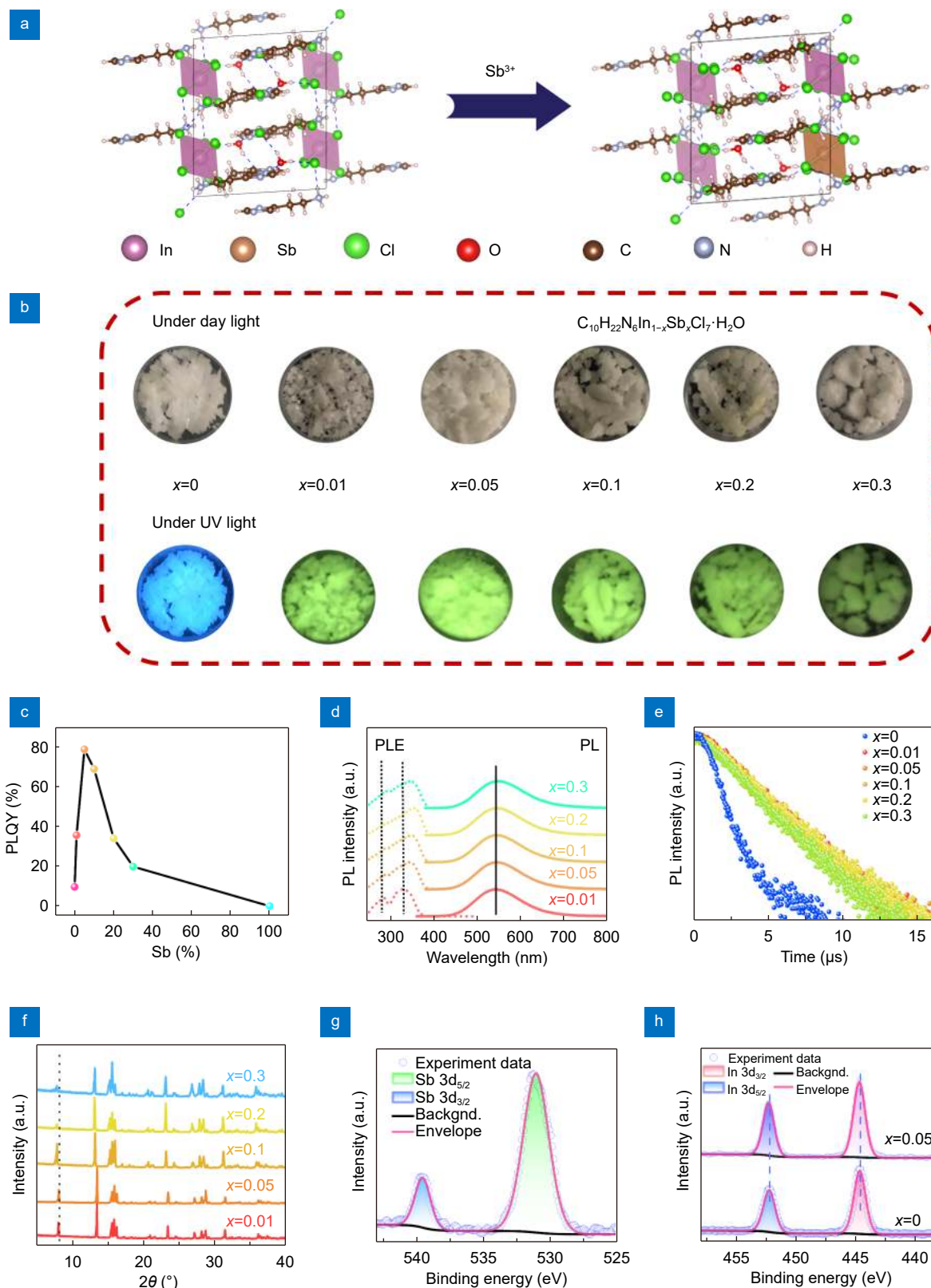


Fig. 1 | (a) Crystal structures of undoped and Sb^{3+} -doped $\text{C}_{10}\text{H}_{22}\text{N}_6\text{InCl}_7\cdot\text{H}_2\text{O}$. (b) Photographs of $\text{C}_{10}\text{H}_{22}\text{N}_6\text{In}_{1-x}\text{Sb}_x\text{Cl}_7\cdot\text{H}_2\text{O}$ under day light and UV light. (c) PLQY, (d) Normalized PLE and PL spectra, (e) PL decay curve, (f) Powder XRD patterns of $\text{C}_{10}\text{H}_{22}\text{N}_6\text{In}_{1-x}\text{Sb}_x\text{Cl}_7\cdot\text{H}_2\text{O}$. (g) XPS spectra of Sb 3d in $\text{C}_{10}\text{H}_{22}\text{N}_6\text{In}_{0.95}\text{Sb}_{0.05}\text{Cl}_7\cdot\text{H}_2\text{O}$. (h) XPS spectra of In 3d in pristine $\text{C}_{10}\text{H}_{22}\text{N}_6\text{InCl}_7\cdot\text{H}_2\text{O}$ and $\text{C}_{10}\text{H}_{22}\text{N}_6\text{In}_{0.95}\text{Sb}_{0.05}\text{Cl}_7\cdot\text{H}_2\text{O}$.

in the monoclinic $P2_1/n$ space group, forming a 1D organic-inorganic hybrid halides (Fig. S6). $C_5H_{11}N_3SbCl_5$ has a PL spectrum with broadband characteristics with dominant peaks at 437 nm and 593 nm (Fig. S7). $C_5H_{11}N_3SbCl_5$ exhibits a low PLQY due to the short distance between Sb ions. The introduction of Sb^{3+} into $C_{10}H_{22}N_6InCl_7 \cdot H_2O$ results in a strong green emission centered at 545 nm (Fig. 1(d)). As the amount of Sb was increased, the emission wavelength of $C_{10}H_{22}N_6In_{1-x}Sb_xCl_7 \cdot H_2O$ remained constant (Table S2). Additionally, the photoluminescence excitation (PLE) spectra showed two primary peaks which are assigned to the characteristic 1S_0 to 1P_1 and 3P_1 transitions of Sb^{3+} , respectively. Sb-doping induces an impurity level in the bandgap, leading to a reduced bandgap. The PLE spectra shows a red-shift trend with increasing the Sb^{3+} concentration due to the Sb-Sb interaction which results in a further reduction of the band gap. As shown in Figs. 1(e) and S8, the PL decay curves for both the doped samples were fitted using a single-exponential function, revealing an average lifetime of 4.3 μs for the doped samples, suggesting that the origin of Sb^{3+} emission.

As illustrated in Fig. 1(f), all the samples exhibit similar XRD patterns. The small shifts towards lower angles observed in these patterns are attributed to the expansion of crystal lattice in doped samples, where the bond length of Sb-Cl (1.11 Å) is shorter than that of In-Cl (1.38 Å)²⁷. The successful introduction of Sb dopants into the crystal can be verified through the X-ray photoelectron spectra (XPS) (Fig. S9). As illustrated in Fig. 1(g), the peaks observed at 539.5 and 531.0 eV are attributed to the Sb 3d_{3/2} and Sb 3d_{5/2} components, respectively. The observation of these peaks serves as a clear confirmation of the presence of Sb in the sample. Furthermore, the introduction of Sb^{3+} results in the shifting of two characteristic peaks of In 3d_{3/2} and In 3d_{5/2} towards higher binding energies (Fig. 1(h)). Accordingly, both In and Sb in the metal halide frameworks are presented in the form of +3 oxidation state, while Cl is presented in the form of -1 valence state (Fig. S10). As shown in Fig. S11, the energy dispersive spectroscopy (EDS) mapping shows a uniform distribution of In and Sb elements in Sb-doped $C_{10}H_{22}N_6InCl_7 \cdot H_2O$, implying the uniform doping and negligible element segregation.

To identify the origin of the green emission, we conducted a series of experiments. As $C_{10}H_{22}N_6In_{0.95}Sb_{0.05}Cl_7 \cdot H_2O$ exhibited the strongest emission, we performed further experiments on this

compound. When excitation wavelength increases from 260 to 370 nm, the emission wavelength of $C_{10}H_{22}N_6In_{0.95}Sb_{0.05}Cl_7 \cdot H_2O$ remains unchanged. Under different excitation wavelength, the unchanged PL spectra and FWHM values of $C_{10}H_{22}N_6In_{1-x}Sb_xCl_7$ indicate that its emission originates from the same excited states (Fig. 2(a))^{28–30}. As shown in Fig. 2(b), the PL intensity of $C_{10}H_{22}N_6In_{0.95}Sb_{0.05}Cl_7 \cdot H_2O$ is directly proportional to the excited power density. This implies that its emission may not originate from defects, as evidenced by the absence of a saturated intensity even at high excitation power density³¹.

To gain a better understanding of the origins of the strong green emission observed in $C_{10}H_{22}N_6In_{0.95}Sb_{0.05}Cl_7 \cdot H_2O$, we conducted temperature-dependent PL spectra measurements (Fig. 2(c)). The PL intensity of green emission centered at 545 nm gradually increases when temperature decreases from 300 K to 80 K, which is attributed to the decreased occurrence of nonradiative transitions at the lower temperatures. Figure 2(d) displays the integrated photoluminescence intensity of $C_{10}H_{22}N_6In_{0.95}Sb_{0.05}Cl_7 \cdot H_2O$ at varying temperatures. Therefore, we calculated the binding energy (E_a) of the STEs using the Arrhenius equation presented below³²:

$$I(T) = \frac{I_0}{1 + Ae^{(-E_a/k_B T)}}, \quad (1)$$

where I_0 represents the integrated PL intensity at 0 K, k_B denotes the Boltzmann constant and A refers to the pre-exponential coefficient. The binding energy of $C_{10}H_{22}N_6In_{0.95}Sb_{0.05}Cl_7 \cdot H_2O$ was calculated to be 99.1 meV, as shown in Fig. 2(d). This value is larger than that of traditional 3D perovskites (20–40 meV)^{33–35}. The calculated E_a is greater than the thermal ionization energy (~26 meV at 300 K), indicating that excitons can remain stable at room temperature. The substantial exciton binding energy contributes to intense radiative recombination, resulting in a high PLQY. We evaluated the electron-phonon coupling effect by examining the relationship between the FWHM of photoluminescence and temperature (Fig. 2(e)). Moreover, we calculate the Huang-Rhys factor (S) and phonon frequency ($\hbar\omega_{\text{phonon}}$) using the following formula³⁶:

$$FWHM = 2.36\sqrt{S}\hbar\omega_{\text{phonon}}\sqrt{\coth\frac{\hbar\omega_{\text{phonon}}}{2k_B T}}, \quad (2)$$

where k_B denotes the Boltzmann constant and T refers to temperature. The calculated S value and phonon

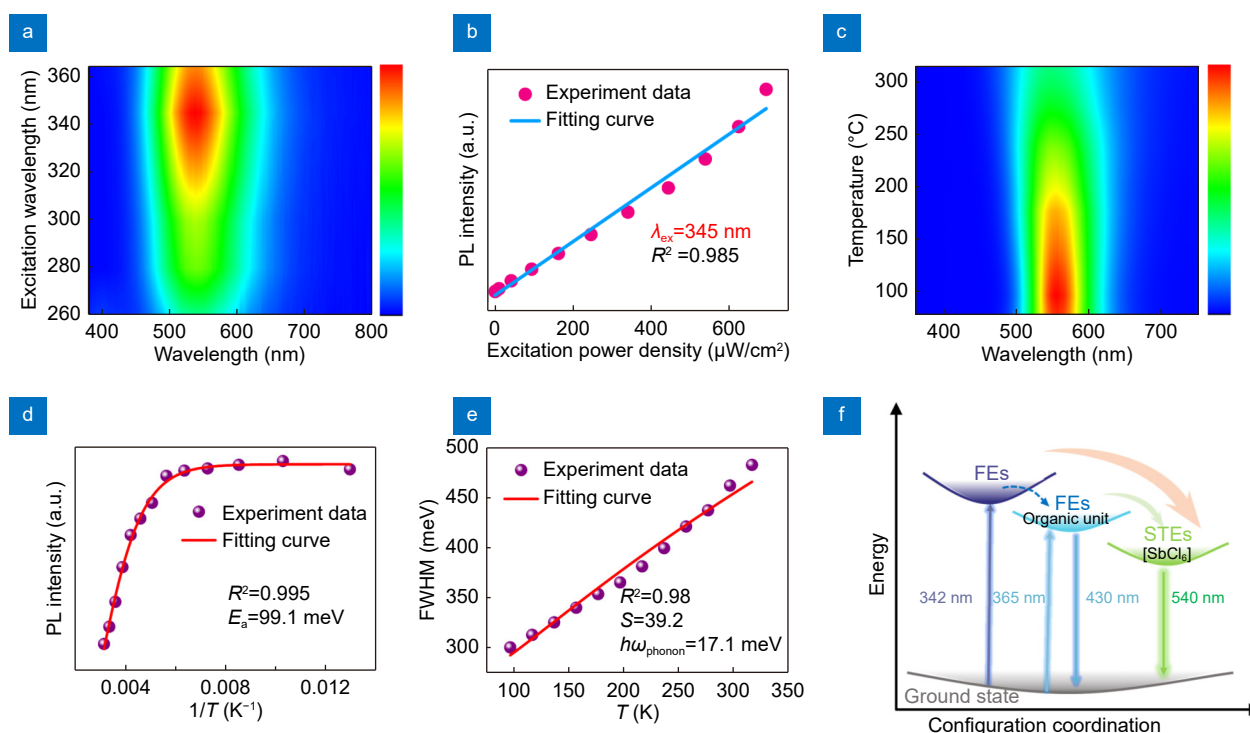


Fig. 2 | (a) PL of $C_{10}H_{22}N_6In_{0.95}Sb_{0.05}Cl_7 \cdot H_2O$ under different excitation wavelengths. (b) PL intensity of $C_{10}H_{22}N_6In_{0.95}Sb_{0.05}Cl_7 \cdot H_2O$ as a function of excitation powers. (c) PL spectra of $C_{10}H_{22}N_6In_{0.95}Sb_{0.05}Cl_7 \cdot H_2O$ under different temperatures. (d) Fitting curve between integrated PL intensity of $C_{10}H_{22}N_6In_{0.95}Sb_{0.05}Cl_7 \cdot H_2O$ and temperature. (e) The correlation between FWHM of the $C_{10}H_{22}N_6In_{0.95}Sb_{0.05}Cl_7 \cdot H_2O$ and temperature. (f) Schematic diagram of the photophysical processes.

frequency are found to be 39.2 and 17.1 meV, respectively, indicating a strong electron-phonon coupling that can easily generate STEs for $C_{10}H_{22}N_6In_{0.95}Sb_{0.05}Cl_7 \cdot H_2O$. Therefore, the emission mechanism of STEs was confirmed due to the features such as microsecond decay time, large Stokes shift, strong electron-phonon coupling, and broadband emission. Figure 2(f) shows the potential emission mechanism of $C_{10}H_{22}N_6In_{1-x}Sb_xCl_7 \cdot H_2O$. Upon excitation with UV light, the electrons can jump from the ground state to the excited state and subsequently undergo intersystem crossing from a singlet state to a triplet self-trapped state caused by lattice distortion, which results in an effective green emission.

The stability of $C_{10}H_{22}N_6In_{0.95}Sb_{0.05}Cl_7 \cdot H_2O$ were investigated. As illustrated in Fig. S12, the PL intensity remains almost unchanged when the samples were irradiated for 420 min under a 365 nm UV irradiation. Figure. S13 shows the PL intensity of the $C_{10}H_{22}N_6In_{0.95}Sb_{0.05}Cl_7 \cdot H_2O$, which retains more than 95% of its original PL intensity even upon heating at 80 °C for 420 minutes. After storing the $C_{10}H_{22}N_6In_{0.95}Sb_{0.05}Cl_7 \cdot H_2O$ crystals in atmosphere for 30 days, their XRD patterns don't show obvious change compared with preparing ones, and their emission in-

tensity maintains 90% of the initial value (Fig. S14). All of the above results indicate the good stability of synthesized samples.

As reported by previous studies, Sb^{3+} -doped hybrid metal halides predominantly emit yellow or red light^{36–38}. The green light emission of the samples may result from a robust hydrogen bond network that influences the distortion of the $[SbCl_6]^{3-}$ polyhedron's excited state structure, thereby retaining it at a higher excited state energy level and emitting green light. The thermogravimetric analysis (TGA) curve shows a weight loss from 25 to 140 °C for $C_{10}H_{22}N_6In_{0.95}Sb_{0.05}Cl_7 \cdot H_2O$, correlating with the loss of H_2O in the structure (Fig. S15). After removing the water molecules, $C_{10}H_{22}N_6In_{0.95}Sb_{0.05}Cl_7$ underwent a red shift in PL emission, resulting in yellow emission, as shown in Fig. 3(a). After heating, the emission wavelength of $C_{10}H_{22}N_6In_{0.95}Sb_{0.05}Cl_7 \cdot H_2O$ increased from 540 to 570 nm, as depicted in the Fig. 3(b) and 3(c). The breaking of the hydrogen bond network and the existence of larger excited state structural changes of the molecule are responsible for the observed phenomenon. Removing water molecules caused a larger degree of excited state structural distortion of the molecule, which created deeper energy levels of STEs level. This is

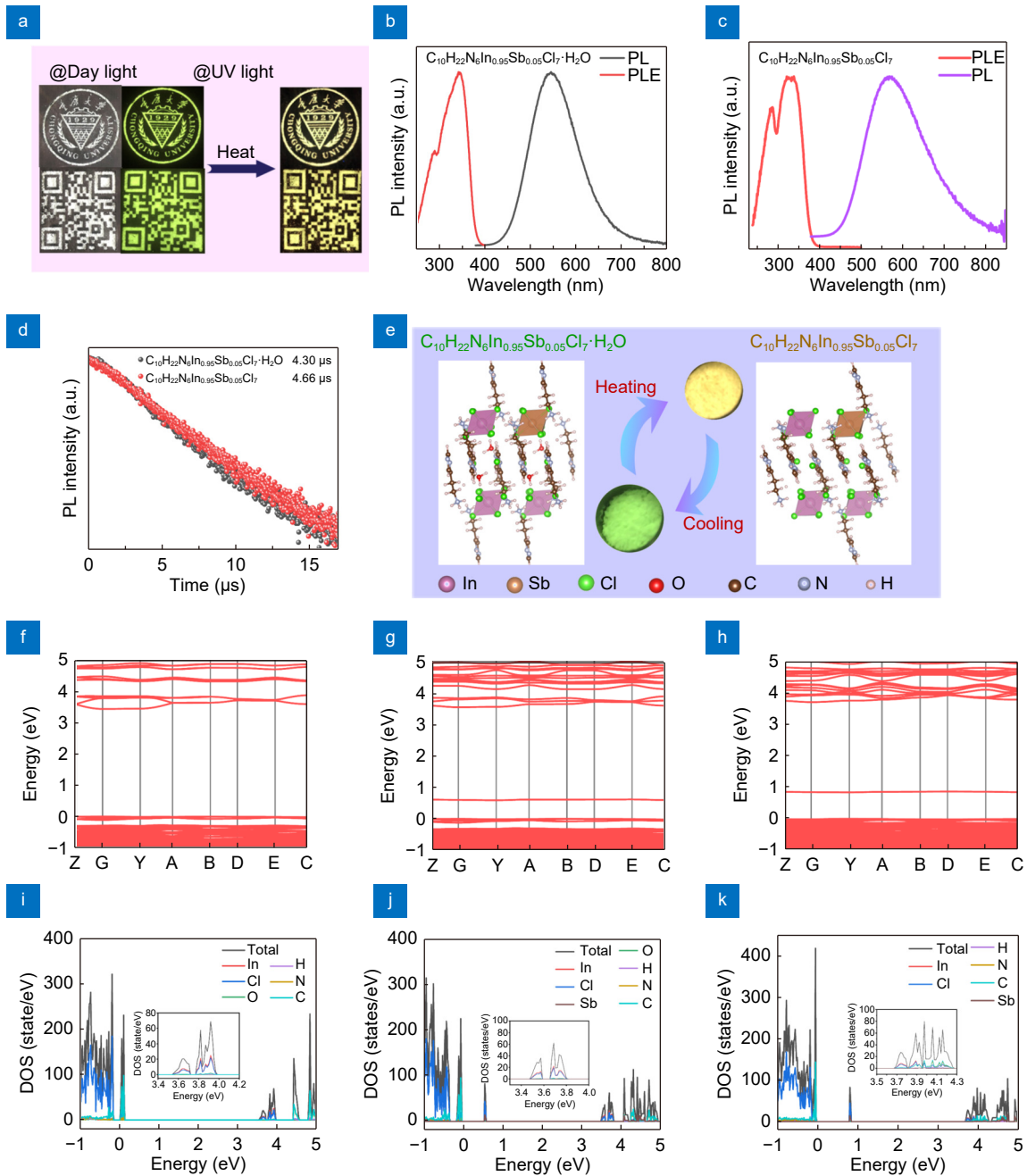


Fig. 3 | (a) Patterned images of $C_{10}H_{22}N_6In_{0.95}Sb_{0.05}Cl_7 \cdot H_2O$ and $C_{10}H_{22}N_6In_{0.95}Sb_{0.05}Cl_7$ under day light and UV light. Normalized PLE spectra and PL spectra of (b) $C_{10}H_{22}N_6In_{0.95}Sb_{0.05}Cl_7 \cdot H_2O$ and (c) $C_{10}H_{22}N_6In_{0.95}Sb_{0.05}Cl_7$. (d) PL decay curve of $C_{10}H_{22}N_6In_{0.95}Sb_{0.05}Cl_7 \cdot H_2O$ and $C_{10}H_{22}N_6In_{0.95}Sb_{0.05}Cl_7$. (e) The crystal structure of Sb^{3+} -doped $C_{10}H_{22}N_6InCl_7 \cdot H_2O$ before and after heating. DFT electronic structures of (f) $C_{10}H_{22}N_6InCl_7 \cdot H_2O$, (g) Sb^{3+} -doped $C_{10}H_{22}N_6InCl_7 \cdot H_2O$ and (h) Sb^{3+} -doped $C_{10}H_{22}N_6InCl_7$. Density of states of (i) $C_{10}H_{22}N_6InCl_7 \cdot H_2O$, (j) Sb^{3+} -doped $C_{10}H_{22}N_6InCl_7 \cdot H_2O$ and (k) Sb^{3+} -doped $C_{10}H_{22}N_6InCl_7$.

evidenced by the increase of PL lifetime from 4.3 μs to 4.66 μs due to the greater excited state distortion (Fig. 3(d)). Due to dominant STEs mechanism in Sb^{3+} -doped $C_{10}H_{22}N_6InCl_7 \cdot H_2O$, its emission properties can be modulated by excited states induced from distorted structures. After removing the water molecules and breaking the hydrogen bond networks, the Raman in-

tensity of A_{1g} increases (Fig. S16), corresponding to larger structural distortion. As a result, red shifts of PL spectra and longer PL lifetime are found in Fig. 3(b–d). Additionally, the $C_{10}H_{22}N_6In_{0.95}Sb_{0.05}Cl_7 \cdot H_2O$ displayed a change in luminescence from yellow to green after absorbing water molecules, which suggests that the process was reversible. Density functional theory (DFT)

theoretical calculations revealed that when water molecules were removed, the degree of distortion of $[\text{SbCl}_6]^{3-}$ octahedra in the calculated crystal structure was altered (Fig. 3(e)). The distortion degree of the $[\text{SbCl}_6]^{3-}$ octahedrons is evaluated using equation^{38–40}:

$$\lambda_{\text{oct}} = \frac{1}{6} \sum_{i=1}^6 \left[\frac{d_i - d_0}{d_0} \right]^2, \quad (3)$$

where d_0 is the average Sb-Cl bond length, d_i are the six individual Sb-Cl bond lengths. The λ_{oct} of Sb^{3+} doped $\text{C}_{10}\text{H}_{22}\text{N}_6\text{InCl}_7 \cdot \text{H}_2\text{O}$ is 3.13×10^{-4} , while the corresponding values of Sb^{3+} doped $\text{C}_{10}\text{H}_{22}\text{N}_6\text{InCl}_7 \cdot \text{H}_2\text{O}$ is 9.22×10^{-4} due to the breaking of the hydrogen bond network.

To further investigate the optoelectronic properties of undoped and Sb^{3+} doped $\text{C}_{10}\text{H}_{22}\text{N}_6\text{InCl}_7 \cdot \text{H}_2\text{O}$, we analyzed the band structures through the DFT framework. The crystal structure used in the theory calculation is depicted in Fig. S17. The formation of STEs generally requires low electronic dimensionality. Figure 3(f–h) depict the nearly flat conduction band (CB) and valence band (VB) of undoped and Sb^{3+} -doped $\text{C}_{10}\text{H}_{22}\text{N}_6\text{InCl}_7 \cdot \text{H}_2\text{O}$, as well as Sb^{3+} -doped $\text{C}_{10}\text{H}_{22}\text{N}_6\text{InCl}_7$, indicating a high degree of electronic state localization that promotes STE formation. After introducing Sb^{3+} ions, the bandgap of the sample decreased from 3.41 eV to 2.90 eV, attributed to the introduction of Sb ion level. This corresponds to the red shift observed in their PLE spectra. After removing water molecules, the bandgap of the sample was 2.83 eV, which may also lead to red shift in luminescence. $\text{C}_5\text{H}_{11}\text{N}_3\text{SbCl}_5$ shows a lower bandgap of 2.58 eV compared to $\text{C}_{10}\text{H}_{22}\text{N}_6\text{InCl}_7 \cdot \text{H}_2\text{O}$, as presented in Fig. S18. As shown in the total and orbital-resolved partial density of states, both the top of valance bands is derived from C and N orbitals, while the bottom of conduction band is dominated by In and Cl orbitals for $\text{C}_{10}\text{H}_{22}\text{N}_6\text{InCl}_7 \cdot \text{H}_2\text{O}$ (Fig. 3(i)). Figure 3(j, k) depict that the valence band maximum consists primarily of Sb and Cl states, while the conduction band minimum has a mixed character of In and Cl for both Sb^{3+} -doped $\text{C}_{10}\text{H}_{22}\text{N}_6\text{InCl}_7 \cdot \text{H}_2\text{O}$ and Sb^{3+} -doped $\text{C}_{10}\text{H}_{22}\text{N}_6\text{InCl}_7$.

Based on its unique optical properties, an anticounterfeiting label was fabricated using the as-synthesized $\text{C}_{10}\text{H}_{22}\text{N}_6\text{In}_0.95\text{Sb}_0.05\text{Cl}_7$. To preventing from water, $\text{C}_{10}\text{H}_{22}\text{N}_6\text{In}_0.95\text{Sb}_0.05\text{Cl}_7$ was coated in PMMA. As shown in Fig. 4(a), the flowers were coated by $\text{C}_{10}\text{H}_{22}\text{N}_6\text{In}_0.95\text{Sb}_0.05\text{Cl}_7 @ \text{PMMA}$, while the butterfly and

bee were coated by $\text{C}_{10}\text{H}_{22}\text{N}_6\text{In}_0.95\text{Sb}_0.05\text{Cl}_7$. Both the butterfly and bee emit a yellow emission under 365 nm irradiation before absorbing water and turn to green emission upon 365 nm excitation after absorbing water molecules. An information encryption model, representing “8888”, was constructed by combining $\text{C}_{10}\text{H}_{22}\text{N}_6\text{InCl}_7 \cdot \text{H}_2\text{O}$, $\text{C}_{10}\text{H}_{22}\text{N}_6\text{In}_0.95\text{Sb}_0.05\text{Cl}_7$ and $\text{C}_{10}\text{H}_{22}\text{N}_6\text{In}_0.95\text{Sb}_0.05\text{Cl}_7 @ \text{PMMA}$. As shown in Fig. 4(b), the fake number information “8888” is apparent under daylight. Upon excitation with 365 nm UV light, referred to as the first decryption, another fake information “1929” in the template emerges. However, the actual information of “1525” can be observed under 365 nm excitation after absorbing water molecules. As shown in Fig. 4(c), the water-responsive photoluminescent behaviors of $\text{C}_{10}\text{H}_{22}\text{N}_6\text{In}_0.95\text{Sb}_0.05\text{Cl}_7$ and $\text{C}_{10}\text{H}_{22}\text{N}_6\text{In}_0.95\text{Sb}_0.05\text{Cl}_7 @ \text{PMMA}$ was utilized to construct a dual-input logic gate. According to Fig. 4(d), input A is defined as the sampling signal, with $\text{C}_{10}\text{H}_{22}\text{N}_6\text{In}_0.95\text{Sb}_0.05\text{Cl}_7$ represented as “1” and $\text{C}_{10}\text{H}_{22}\text{N}_6\text{In}_0.95\text{Sb}_0.05\text{Cl}_7 @ \text{PMMA}$ represented as “0”. Additionally, input B was designated as the environmental signal, where the process of water absorption is represented as “1” and the absence of water absorption is represented as “0”. For the output signal, we defined green emission as “1” and yellow emission as “0”. The logical gate will only be activated when both input A and B are 1, which corresponds to the green emission of the samples after absorbing water molecules. It is worth noting that this doping strategy is applicable to other compounds, providing a new direction for designing optical encryption applications.

Conclusions

In summary, we synthesized $\text{C}_{10}\text{H}_{22}\text{N}_6\text{InCl}_7 \cdot \text{H}_2\text{O}$ and Sb^{3+} doped $\text{C}_{10}\text{H}_{22}\text{N}_6\text{InCl}_7 \cdot \text{H}_2\text{O}$ using an antisolvent diffusion method. Sb^{3+} doped $\text{C}_{10}\text{H}_{22}\text{N}_6\text{InCl}_7 \cdot \text{H}_2\text{O}$ shows strong broadband green light emission peaking at 540 nm and a high PLQY of 80%. The hydrogen bond network limits the structural distortion of the excited state of the inorganic cluster, which plays an important role in the emission of Sb^{3+} doped $\text{C}_{10}\text{H}_{22}\text{N}_6\text{InCl}_7 \cdot \text{H}_2\text{O}$. Breaking the hydrogen bond network causes Sb^{3+} -doped $\text{C}_{10}\text{H}_{22}\text{N}_6\text{InCl}_7 \cdot \text{H}_2\text{O}$ to emit a yellow light. Therefore, the pattern based on transformed Sb^{3+} -doped $\text{C}_{10}\text{H}_{22}\text{N}_6\text{InCl}_7 \cdot \text{H}_2\text{O}$ has been achieved and applied in the digital encryption and decryption as well as optical logical “AND” gate. Our findings expand the understanding

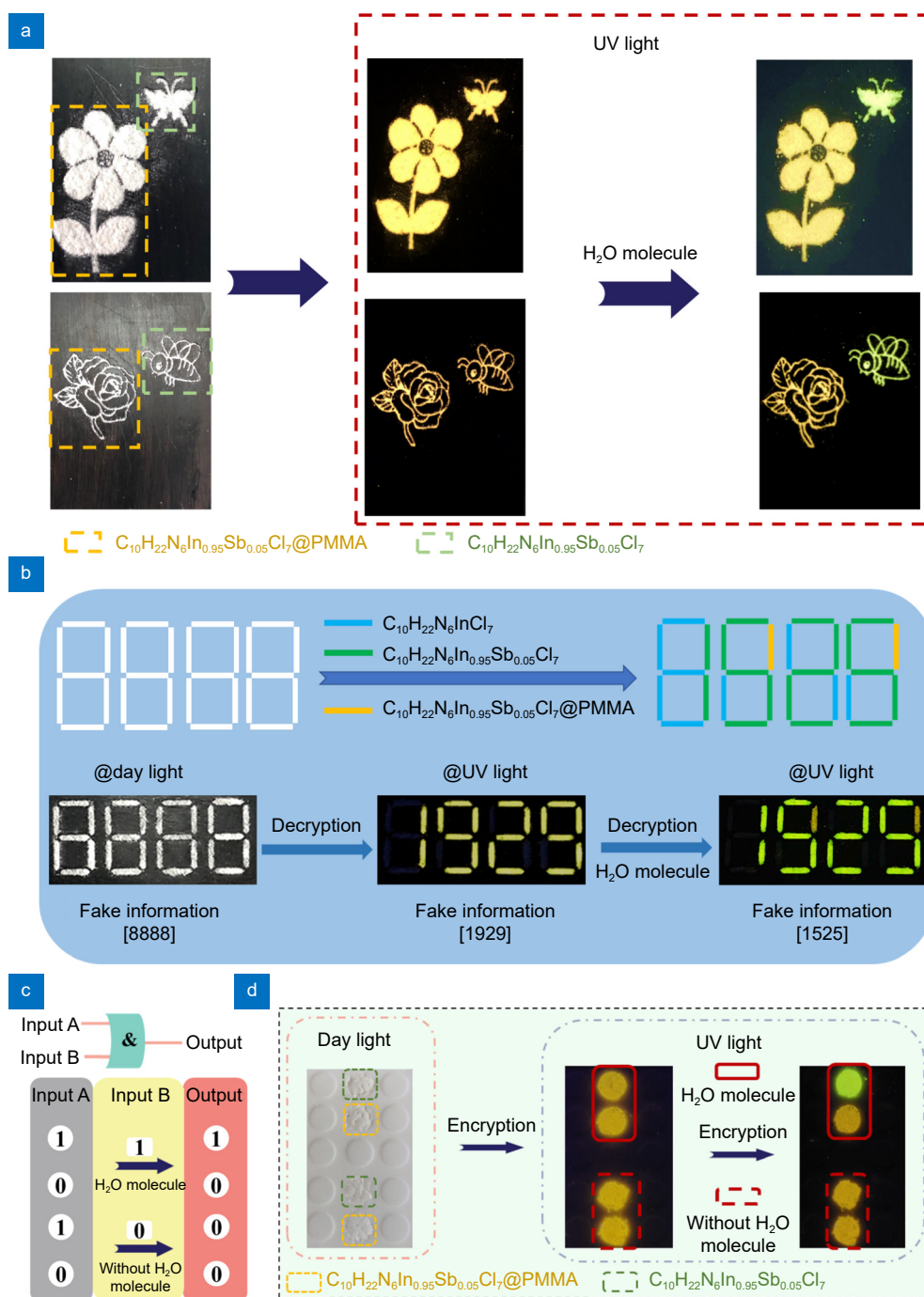


Fig. 4 | (a) Photographs of patterns composed of $C_{10}H_{22}N_6In_{0.95}Sb_{0.05}Cl_7$ and $C_{10}H_{22}N_6In_{0.95}Sb_{0.05}Cl_7@PMMA$. (b) Information encryption process produced by $C_{10}H_{22}N_6In_{0.95}Sb_{0.05}Cl_7 \cdot H_2O$ and $C_{10}H_{22}N_6In_{0.95}Sb_{0.05}Cl_7 \cdot H_2O @PMMA$. (c) Design of optical AND logical gate produced by $C_{10}H_{22}N_6In_{0.95}Sb_{0.05}Cl_7 \cdot H_2O$ and $C_{10}H_{22}N_6In_{0.95}Sb_{0.05}Cl_7 \cdot H_2O @PMMA$. (d) The experimental demonstration of optical AND logical gate.

of how the local coordination structure influences the photophysical mechanism in Sb^{3+} -doped metal halides and provide a novel method to control the STE emission.

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Author contributions

D. H. Liang, Saif M. H. Qaid, and S. Y. Zhao contributed to the experiment-

al design. D. H. Liang performed the experimental studies. Q. K. Qian performed computational study. D. H. Liang, W. S. Cai, B. B. Luo and Z. G. Zang prepared the manuscript. All authors reviewed and revised the manuscript in several steps and approved the final version of the manuscript.

Competing interests

The authors declare no competing financial interests.

Supplementary information

The authors declare no competing financial interests.

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